## NSN 5961-00-764-3218

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View Online at https://aerobasegroup.com/nsn/5961-00-764-3218 **Inclosure Material:** Metal **Overall Length:** 1.600 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 300.0 breakover voltage, dc **Current Rating Per Characteristic:** 70.00 amperes source cutoff current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud **Specification Data:** 80131-release3317 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0